Diode Semiconductor Device - Page 1 of 1



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In	closure Material:
GI	ass
0	verall Length:
0.2	200 inches
Те	erminal Length:
0.9	900 inches
0	verall Diameter:
0.	180 inches
M	ounting Method:
Τe	erminal
Fe	eatures Provided:
He	ermetically sealed case
Se	emiconductor Material:
Si	licon
Vo	oltage Rating In Volts Per Characteristic:
20	0.0 reverse voltage, peak
С	urrent Rating Per Characteristic:
1.0	00 microamperes reverse current, dc
M	aximum Operating Tempurature Per Measurement Point:
20	0.0 degrees celsius junction
Τe	erminal Type And Quantity:
2	uninsulated wire lead
Sł	nelf Life:
N/	a
Uı	nit Of Measure:
De	emilitarization:
No	
Fi	ig:
A1	10a0